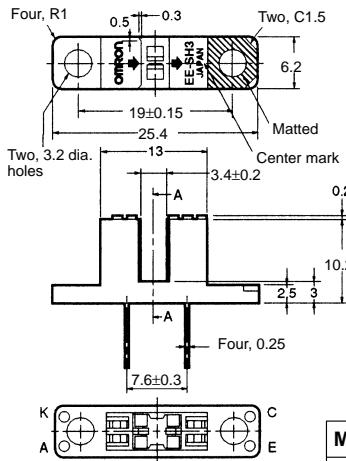


# EE-SH3 Series

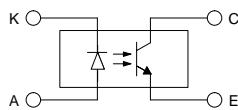
## Photomicrosensor (Transmissive)

### ■ Dimensions

Note: All units are in millimeters unless otherwise indicated.



**Internal Circuit**



Terminal No.	Name
A	Anode
K	Cathode
C	Collector
E	Emitter

Unless otherwise specified, the tolerances are as shown below.

Dimensions	Tolerance
3 mm max.	$\pm 0.2$
$3 < \text{mm} \leq 6$	$\pm 0.24$
$6 < \text{mm} \leq 10$	$\pm 0.29$
$10 < \text{mm} \leq 18$	$\pm 0.35$
$18 < \text{mm} \leq 30$	$\pm 0.42$

### ■ Features

- High-resolution model with a 0.2-mm-wide or 0.5-mm-wide sensing aperture, high-sensitivity model with a 1-mm-wide sensing aperture, and model with a horizontal sensing aperture are available.
- Solder terminal models:  
EE-SH3/-SH3-CS/-SH3-DS/-SH3-GS
- PCB terminal models:  
EE-SH3-B/-SH3-C/-SH3-D/-SH3-G

### ■ Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Rated value
Emitter	Forward current	I <sub>F</sub> 50 mA (see note 1)
	Pulse forward current	I <sub>FP</sub> 1 A (see note 2)
	Reverse voltage	V <sub>R</sub> 4 V
Detector	Collector-Emitter voltage	V <sub>CEO</sub> 30 V
	Emitter-Collector voltage	V <sub>ECO</sub> ---
	Collector current	I <sub>C</sub> 20 mA
	Collector dissipation	P <sub>C</sub> 100 mW (see note 1)
Ambient temperature	Operating	T <sub>opr</sub> -25°C to 85°C
	Storage	T <sub>stg</sub> -30°C to 100°C
Soldering temperature		T <sub>sol</sub> 260°C (see note 3)

- Note:
- Refer to the temperature rating chart if the ambient temperature exceeds 25°C.
  - The pulse width is 10 µs maximum with a frequency of 100 Hz.
  - Complete soldering within 10 seconds.

### ■ Electrical and Optical Characteristics (Ta = 25°C)

Item	Symbol	Value				Condition	
		EE-SH3(-B)	EE-SH3-C(S)	EE-SH3-D(S)	EE-SH3-G(S)		
Emitter	Forward voltage	V <sub>F</sub>	1.2 V typ., 1.5 V max.			I <sub>F</sub> = 30 mA	
	Reverse current	I <sub>R</sub>	0.01 µA typ., 10 µA max.			V <sub>R</sub> = 4 V	
	Peak emission wavelength	λ <sub>P</sub>	940 nm typ.			I <sub>F</sub> = 20 mA	
Detector	Light current	I <sub>L</sub>	0.5 to 14 mA typ.	1 to 28 mA typ.	0.1 mA min.	0.5 to 14 mA	I <sub>F</sub> = 20 mA, V <sub>CE</sub> = 10 V
	Dark current	I <sub>D</sub>	2 nA typ., 200 nA max.				V <sub>CE</sub> = 10 V, 0 ℓx
	Leakage current	I <sub>LEAK</sub>	---				---
	Collector-Emitter saturated voltage	V <sub>CE</sub> (sat)	0.1 V typ., 0.4 V max.	---	0.1 V typ., 0.4 V max.	I <sub>F</sub> = 20 mA, I <sub>L</sub> = 0.1 mA	
	Peak spectral sensitivity wavelength	λ <sub>P</sub>	850 nm typ.				V <sub>CE</sub> = 10 V
Rising time		tr	4 µs typ.				V <sub>CC</sub> = 5 V, R <sub>L</sub> = 100 Ω, I <sub>L</sub> = 5 mA
Falling time		tf	4 µs typ.				